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650V N-Channel Silicon Carbide Power MOSFET

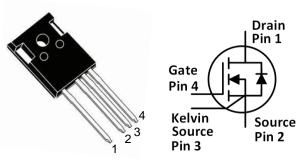
Features

- High blocking voltage with low on-resistance
- High speed switching with low capacitance
- High operating junction temperature capability
- Very fast and robust intrinsic body diode
- Kelvin gate input easing driver circuit design

Applications

- EV chargers
- Server & Telecom PSU
- Solar inverters
- UPS
- High voltage DC/DC converters
- Switch mode power supplies

Package



Top View

Part Number	Package		
DTN70N65SC4	TO247-4		

Absolute Maximum Ratings (T_c=25°C unless otherwise specified)

Symbol	Parameter	Value	Un	Test Conditions	Note
			it		
V _{DS}	Drain-Source voltage	650	V	V _{GS} =0V, I₀=100µA	
V _{GSmax} (DC)	Maximum DC voltage	-5 to 22	V	Static (DC)	
V _{GSmax} (Spike)	Maximum spike voltage	-10 to 25	V	<1% duty cycle, and pulse width<200ns	
V _{GSon}	Recommended turn-on voltage	20±0.5	V		
V _{GSoff}	Recommended turn-off voltage	-3.5 to -2	V		
	Drain current (continuous)	72	Α	V _{GS} =20V, T _C =25°C	
D		58	Α	V _{GS} =20V, T _C =100°C	Fig. 21
I _{DM}	Drain current (pulsed)	180	А	Pulse width limited by SOA	Fig. 24
Ртот	Total power dissipation	348	W	T _c =25°C	Fig. 22
T _{stg}	Storage temperature range	-55 to 175	°C		
Τı	Operating junction temperature	-55 to 175	°C		
Τι	Solder Temperature	260	°C	wave soldering only allowed at leads, 1.6mm from case for 10 s	

Thermal Data

Symbol	Parameter	Value	Unit	Note	
$R_{\theta(J-C)}$	Thermal Resistance from Junction to Case	0.431	°C/W	Fig. 23	

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Electrical Characteristics (Tc=25°C unless otherwise specified)

Symbol	Parameter	Value			Unit	Test Conditions	Note
-		Min.	Тур.	Max.			
I _{DSS}	Zero gate voltage drain current		3	100	μA	V _{DS} =650V, V _{GS} =0V	
GSS	Gate leakage current			±100	nA	V _{DS} =0V, V _{GS} =-5~20V	
	Gate threshold voltage	1.8	3.2	5	V	V _{GS} =V _{DS} , I _D =6.1mA V _{GS} =V _{DS} , I _D =6.1mA @ T _c =175°C	
V_{TH}			2.2				Fig. 8, 9
Ron	Static drain-source on-		40	55	mΩ	V _{GS} =20V, I _D =20A @T _J =25°C	Fig. 4, 5, 6,
	resistance		53		mΩ	V _{GS} =20V, I _D =20A @T _J =175°C	7
Ciss	Input capacitance		2692		рF		Fig. 16
C_{oss}	Output capacitance		179		рF	V _{DS} =600V, V _{GS} =0V,	
C_{rss}	Reverse transfer capacitance		10.8		рF	$f=1MH_z, V_{AC}=25mV$	
Eoss	Coss stored energy		35.6		μJ		Fig. 17
Qg	Total gate charge		110.8		nC	V _{DS} =400V, I _D =20A,	Fig. 18
Q_{gs}	Gate-source charge		26.8		nC	$V_{DS} = 400V$, $I_D = 20A$, $V_{GS} = -5$ to 20V	
Q_{gd}	Gate-drain charge		35.7		nC	VGS=-J tO 20V	
Rg	Gate input resistance		2		Ω	f=1MHz	
Eon	Turn-on switching energy		163.1		μJ		
EOFF	Turn-off switching energy		53.0		μJ	$\begin{array}{c} V_{DS}{=}400V, \ I_{D}{=}30A, \\ V_{GS}{=}{-}2 \ to \ 20V, \\ R_{G(ext)}{=}3.3\Omega, \\ L{=}450\mu H \end{array} \hspace{1.5cm} \mbox{Fig}$	Fig. 19, 20
t _{d(on)}	Turn-on delay time		12.2				
tr	Rise time		17.6		nc		J ,
$t_{\text{d(off)}}$	Turn-off delay time		30.2		ns		
tr	Fall time		12.6				

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Reverse Diode Characteristics (Tc=25°C unless otherwise specified)

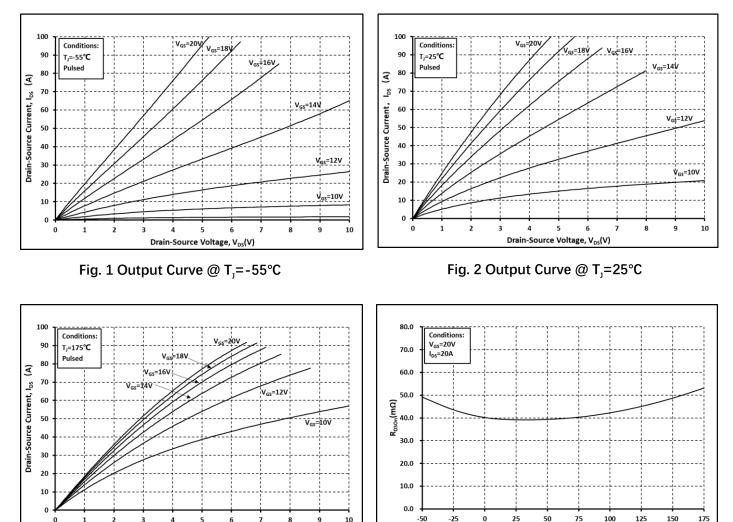
Symbol	Parameter	Value			Unit	Test Conditions	Note
		Min.	Тур.	Max.			
V _{SD}	Diode forward voltage		4.0		V	I _{SD} =20A, V _{GS} =0V	Fig. 10, 11, 12
			3.6		V	I _{SD} =20A, V _{GS} =0V, T _J =175°C	
trr	Reverse recovery time		15.6		ns	$V_{GS} = -2V/+20V,$	
Qrr	Reverse recovery charge		130.3		nC	I _{SD} =30A, V _R =400V, di/dt=1884A/us,	
RRM	Peak reverse recovery current		13.4		А	R _{G(ext)} =15Ω L=450μH	



0

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Typical Performance (curves)



9

10

-50

0

25

Fig. 3 Output Curve @ T₁=175°C

5

Drain-Source Voltage, V_{DS}(V)

6

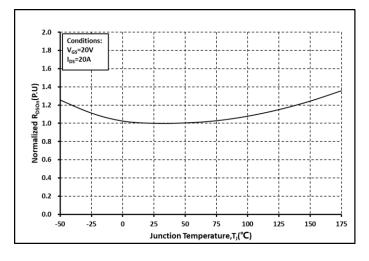


Fig. 5 Normalized Ron vs. Temperature

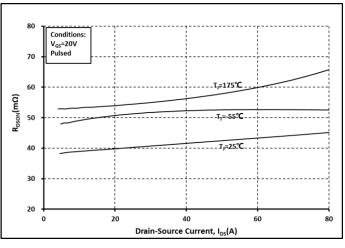
Fig. 4 Ron vs. Temperature

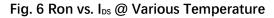
50

Junction Temperature, $T_{J}(^{\circ}C)$

75

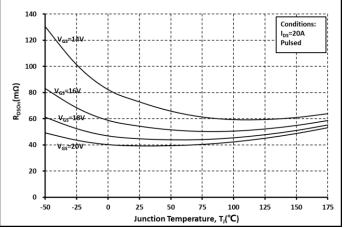
100





175

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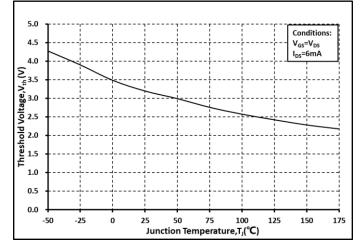


Fig. 9 Threshold Voltage vs. Temperature

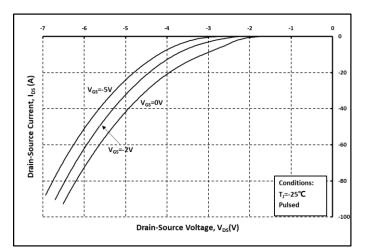


Fig. 11 Body Diode Curves @ $T_3=25^{\circ}C$

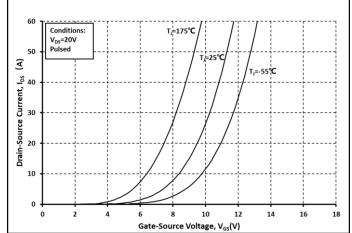


Fig. 8 Transfer Curves @ Various Temperature

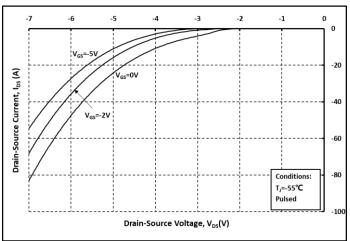


Fig. 10 Body Diode Curves @ T_J=-55°C

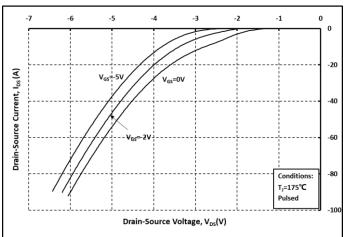


Fig. 12 Body Diode Curves @ T₁=175°C



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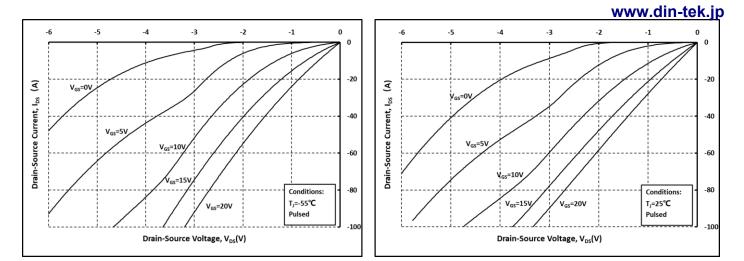


Fig. 13 3rd Quadrant Curves @ T_J=-55°C



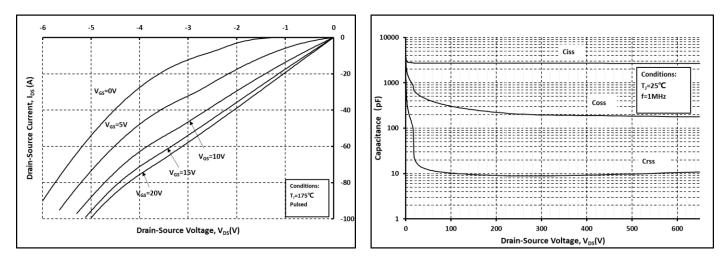


Fig. 15 3rd Quadrant Curves @ T_J=175°C

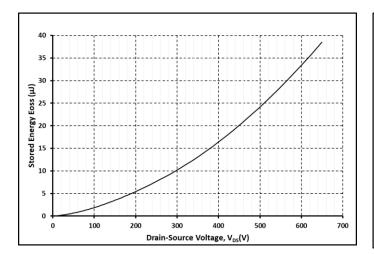


Fig. 17 Output Capacitor Stored Energy

Fig. 16 Capacitance vs. V_{DS}

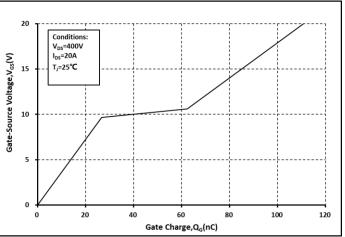
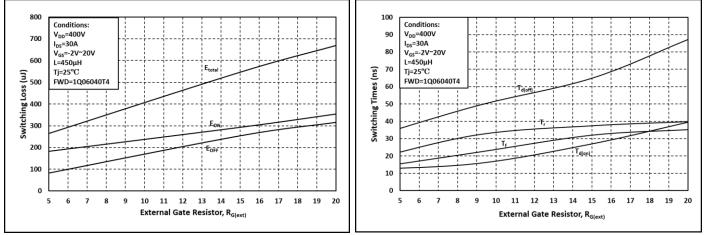


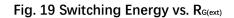
Fig. 18 Gate Charge Characteristics

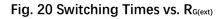


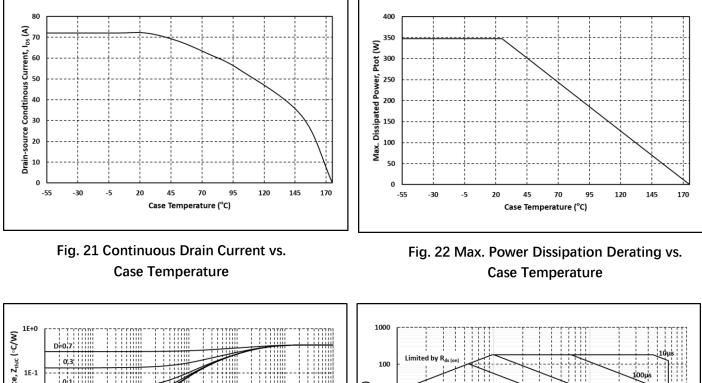
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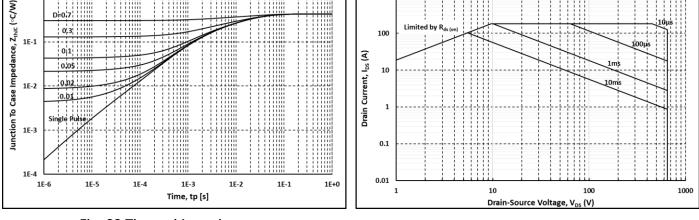


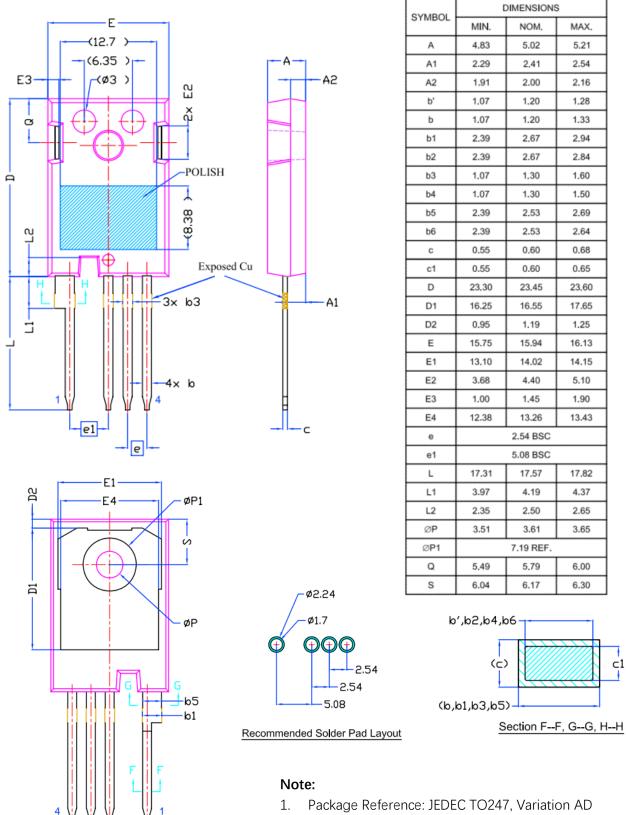
Fig. 23 Thermal Impedance

Fig. 24 Safe Operating Area



Package Information www.din-tek.jp

Package Dimensions



- 2. All Dimensions are in mm
- 3. Slot Required, Notch May Be Rounded
- 4. Dimension D&E Do Not Include Mold Flash

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